

HT16515 1/4 to 1/12 Duty VFD Controller

Features

- · Logic voltage: 5V
- High-voltage output: V_{DD}-35V max.
- Multiple display (16-segment & 12-digit to 24-segment & 4-digit)
- 16×2 matrix key scanning
- · 8 steps dimmer circuit

Applications

- · Consumer products panel function control
- Industrial measuring instrument panel function control

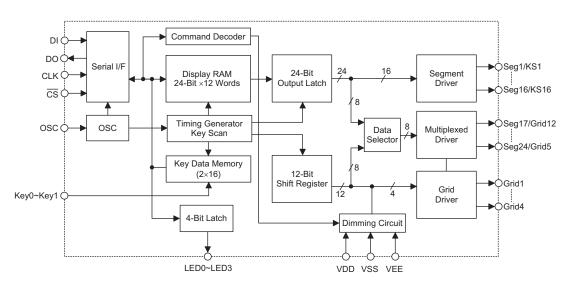
- 4 LED output ports (20mA max.)
- No external resistors necessary for driver output (provides PMOS open-drain and pull-low resistor output)
- Serial interface with MCU (CLK, CS, DI, DO)
- 44-pin QFP package
- Other similar applications for panel function control

General Description

HT16515 is a VFD (Vacuum Fluorescent Display) controller/driver that is driven on a 1/4 to 1/12 duty factor. It consists of 16 segment output lines, 4 grid output lines, 8 segment/grid output drive lines, 4 LED output ports, a control circuit, a display memory, and a key scan circuit.

Serial data inputs to the HT16515 through a three-line serial interface. This VFD controller/driver is an ideal MCU peripheral device.

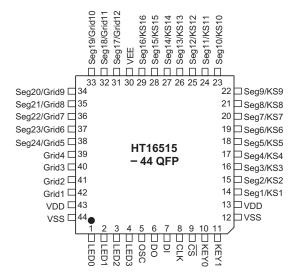
Block Diagram



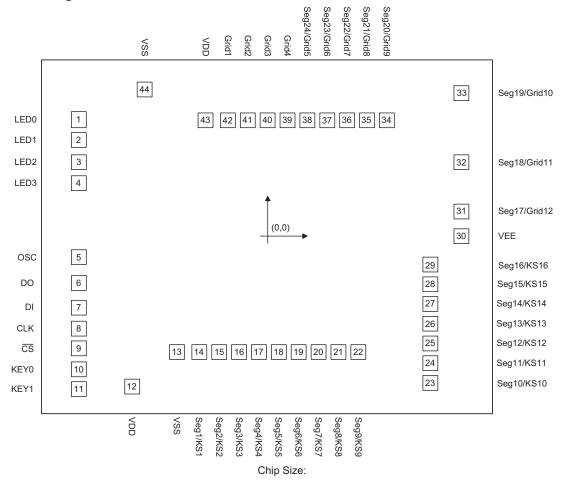
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Pin Assignment



Pad Assignment



^{*} The IC substrate should be connected to VSS in the PCB layout artwork.

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Pad Coordinates Unit: μm

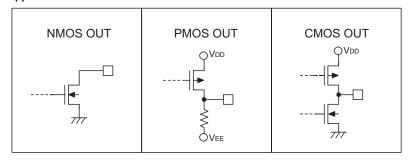
Pad No.	Х	Υ	Pad No.	Х	Υ
1	-962.50	600.00	23	834.10	-754.00
2	-962.50	495.00	24	834.10	-652.60
3	-962.50	380.20	25	834.10	-551.20
4	-962.50	275.20	26	834.10	-449.80
5	-962.50	-107.20	27	834.10	-348.40
6	-962.50	-235.60	28	834.10	-247.00
7	-962.50	-366.00	29	834.10	-145.60
8	-962.50	-471.00	30	987.30	0.50
9	-962.50	-576.00	31	987.30	130.50
10	-962.50	-681.00	32	987.30	382.05
11	-962.50	-786.00	33	987.30	734.05
12	-689.60	-772.45	34	610.30	594.40
13	-460.45	-595.30	35	508.90	594.40
14	-344.25	-595.30	36	407.50	594.40
15	-242.85	-595.30	37	306.10	594.40
16	-141.45	-595.30	38	204.70	594.40
17	-40.05	-595.30	39	103.30	594.40
18	61.35	-595.30	40	1.90	594.40
19	162.75	-595.30	41	-99.50	594.40
20	264.15	-595.30	42	-200.90	594.40
21	365.55	-595.30	43	-317.10	594.40
22	466.95	-595.30	44	-624.50	756.80

Pin Description

Pin No.	Pin Name	I/O	Description
1~4	LED3~LED0	0	LED driver output ports. This is a CMOS output pin and maximum driving current up to +20mA.
5	osc	I	Connected to an external resistor or an RC oscillator circuit.
6	DO	0	Data output pin, output serial data at falling edge of shift clock, starting from the lower bit. This is N-ch open-drain output pin.
7	DI	I	Data input pin, input serial data at rising edge of shift clock, starting from the lower bit.
8	CLK	I	Clock input pin. Reads serial data at the rising edge, and outputs data at the falling edge.
9	CS	I	Initializes serial interface at the rising or falling edge of the HT16515. Then it waits to receive a command. Data input after \overline{CS} has fallen is processed, current processing is stopped, and the serial interface is initialized. While \overline{CS} is high, CLK is ignored.
10, 11	Key0, Key1	I	Key-in data input to these pins are latched at the end of the display cycle.
12, 44	VSS	_	Negative power supply, ground
13, 43	VDD	_	Positive power supply
14~29	Seg1/KS1~Seg16/KS16	0	High voltage output, segment output pins, dual function as key source. This is PMOS open-drain and pull-low resistor output.
30	VEE	_	VFD power supply
31~38	Seg17/Grid12~ Seg24/Grid5	0	High voltage output, these pins are selectable for segment or grid output. This is PMOS open-drain and pull-low resistor output.
39~42	Grid4~Grid1	0	High voltage output, grids output pin. This is PMOS open-drain and pull-low resistor output.



Approximate Internal Connections



Absolute Maximum Ratings

Supply VoltageV _{SS} -0.3V to V _{SS} +6.0V	Operating Temperature–25°C to 75°C
Input Voltage V_{SS} -0.3V to V_{DD} +0.3V	Storage Temperature50°C to 125°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

D.C. Characteristics Ta=25°C

0	Down of the		Test Conditions				1127
Symbol	Parameter	V_{DD}	Conditions	Min.	Тур.	Max.	Unit
V_{DD}	Logic Supply Voltage		_	4.5	5	5.5	V
V_{EE}	VFD Supply Voltage	_	_	0	_	V _{DD} -35	V
f _{OSC}	Oscillation Frequency	5V	R _{OSC} =82kΩ	350	500	650	kHz
R _{PL}	Output Pull-low Resistor	5V	Driver output	40	65	120	kΩ
I _{DD}	Operating Current	5V	No load, VFD display off	_	_	5	mA
I _{OL}	Driver Leakage Current	5V	V _O =V _{DD} -30V, VFD driver off	_	_	-10	μΑ
I _{OL1}	LED Sink Current	5V	V _{OL} =1V, LED0~LED3	20	_	_	mA
I _{OH1}	LED Source Current	5V	V _{OH} =0.9V _{DD} , LED0~LED3	-3	_	_	mA
I _{OH21}	Segment 1~16 Source Current	5V	V _{OH} =V _{DD} -2V	-3	_	_	mA
I _{OH22}	Segment 17~24, Grid 1~4 Source Current	5V	V _{OH} =V _{DD} -2V	-15	_	_	mA
I _{OL3}	DO Sink Current	5V	V _{OL} =0.4V	4	_	_	mA
V _{IH}	"H" Input Voltage		_	0.7V _{DD}	_	V _{DD}	V
V _{IL}	"L" Input Voltage		_	0	_	0.3V _{DD}	V
V _H	Hysteresis Voltage		CLK, D _{IN} , CS	_	0.35	_	V
V _{OH1}	High-level Output Voltage	5V	LED0~LED3, I _{OH1} =-3mA	0.9V _{DD}	_	V _{DD}	V
V _{OL1}	Low-level Output Voltage	5V	LED0~LED3, I _{OL1} =20mA	0	_	1	V
V _{OL2}	Low-level Output Voltage	5V	DO, I _{OL2} =4mA	0	_	0.4	V

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A.C. Characteristics Ta=25°C

Symbol	Parameter	Test Conditions			T	Man	11:4
Symbol	Parameter	V _{DD}	Conditions	Min.	Тур.	Max.	Unit
t _{PHL}	Lania Complex Valtage	5V	CLK→DO	_	_	300	ns
t _{PLH}	Logic Supply Voltage	5V	$C_L=15pF, R_L=10k\Omega$	_	_	300	ns
t _{r1}		5V	C _L =300pF, S1~S16	_	_	2	μS
t _{r2}	Rise Time	5V	C _L =300pF, G1~G4 S17/G12~S24/G5	_	_	0.5	μS
t _f	Fall Time	5V	C _L =300pF, Sn, Gn	_	_	120	μS
t _{max}	Maximum Clock Frequency	5V	Duty=50%	1	_	_	MHz
Ci	Input Capacitance	5V	_	_	_	15	pF
t _{CW}	Clock Pulse Width	5V	_	400	_	_	ns
t _{SW}	Strobe Pulse Width	5V	_	1	_	_	us
t _{SU}	Data Setup Time	5V	_	100	_	_	ns
t _h	Data Hold Time	5V	_	100	_	_	ns
t _{CS}	Clock-Strobe Time	5V	CLK rising edge to CS rising edge	1	_	_	μS
t _W	Wait Time	5V	CLK rising edge to CLK falling edge	1	_	_	μS

Functional Description

Display RAM and Display Mode

The static display RAM stores the data transmitted from an external device to the HT16515 through a serial interface. The contents of the RAM are directly mapped to the contents of the VFD driver. Data in the RAM can be accessed through the data setting, address setting and display control commands. It is assigned as addresses in 8-bit unit as follows:

SEG1 SEG4 SEG8 SEG12 SEG16 SEG20 SEG24

00HL	00H ∪	01H∟	01H υ	02HL	02H∪	DIG1
03HL	03H ∪	04HL	04H ∪	05H∟	05H∪	DIG2
06HL	06H∪	07HL	07H υ	08H∟	08H∪	DIG3
09H _L	09Hu	0AH _L	0AH∪	0BH∟	0BHu	DIG4
0CH _L	0CHυ	0DHL	0DHu	0EHL	0EHu	DIG5
0FHL	0FHu	10HL	10H υ	11H∟	11H∪	DIG6
12HL	12Hυ	13HL	13Hυ	14HL	14H∪	DIG7
15H _L	15H∪	16H∟	16H∪	17H∟	17H∪	DIG8
18HL	18H∪	19HL	19H∪	1AHL	1AHu	DIG9
1BH _L	1BH∪	1CH _L	1CH∪	1DH _L	1DHu	DIG10
1EH _L	1EHυ	1FH∟	1FH∪	20HL	20H ∪	DIG11
21HL	21Η υ	22HL	22H∪	23HL	23H∪	DIG12

b0	b3	b7	
XX	HL	XX	Hυ
Lov	ver	Hig	her
1 h	ite	4 hi	te

Dimming Control

HT16515 provides an 8-step dimmer function on display by controlling the 3-bit binary command code. The full pulse width of grid signal is divided into 16 uniform sections by PWM (pulse width modulation) technology.

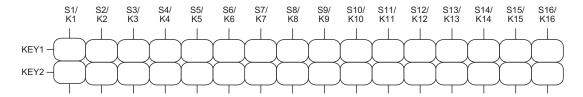
The 16 uniform sections available form an 8-step dimmer via 3-bit binary code. The 8-step dimmer includes 1/16, 2/16, 4/16, 10/16, 11/16, 12/16, 13/16 and 14/16. The 1/16 pulse width indicates minimum lightness. The 14/16 pulse width represents maximum lightness (Refer to the display control command).

Key Matrix and Key-Input Data Storage RAM

The key matrix scans the series key states at each level of the key strobe signal (Seg1/K1~Seg16/K16) output of the HT16515. The key strobe signal outputs are time-multiplexed signals from Seg1/K1~Seg16/K16. The states of inputs K0 and K1 are sampled by strobe signal Seg1/K1~Seg16/K16 and latched into the register.



The key matrix is made up of a 16×2 matrix, as shown below.



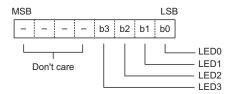
The data of each key is stored as illustrated below, and is read with the read command, starting from the least significant bit.

Key1 Key2 Key1 Key2 Key1 Key2 Key1 Key2 S1/K1 S2/K2 S3/K3 S4/K4 S5/K5 S6/K6 S7/K7 S8/K8 Reading Sequence S10/K10 S9/K9 S11/K11 S12/K12 S13/K13 S14/K14 S15/K15 S16/K16 b4 b1 b2 b3 b5 b6 b7

LED Port

The LED port is of the CMOS output configuration.

Data is written to the LED port with the write command, starting from the least significant bit. In our application (see application circuits), the user adopts an internal NMOS device to a driver LED component by connecting VDD. When a bit of this port is 0, the corresponding LED lights up; when the bit is 1, the LED turns off. The data of bits 4 through 7 are ignored.



Commands

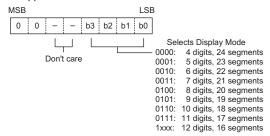
Commands set the display mode and status of the VFD driver.

The first $\frac{1}{CS}$ byte input to the HT16515 through the DI pin after the $\frac{1}{CS}$ pin has fallen, is regarded as a command. If $\frac{1}{CS}$ is set high while commands/data are transmitted, serial communication is initialized, and the commands/data being transmitted are not valid (however, the commands/data previously transmitted remains valid).

• Display mode setting commands

These commands initialize the HT16515 and select the number of segments and the number of grids $(1/4\sim1/12 \text{ duty}, 16 \text{ to } 24 \text{ segments}).$

When these commands are executed, the display is forcibly turned off, and key scanning is also stopped. To resume display, the display command "ON" must be executed. If the same mode is selected, nothing happens.

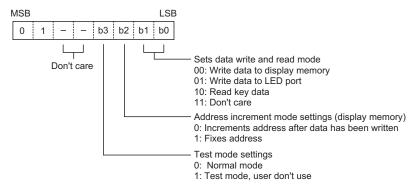


Note: Power-on status: 12-digit, 16 segment mode is selected.



· Data setting commands

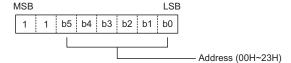
These commands set the data write and data read modes.



Note: power-on status: normal mode operation and address increment mode are set.

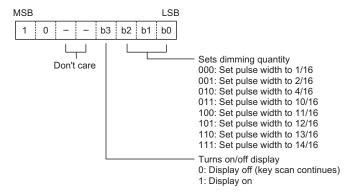
· Address setting commands

These commands set the address of the display memory.



If address 24H or higher is set, data is ignored until a valid address is set. Note: power-on status: the address is set to 00H.

• Display control commands

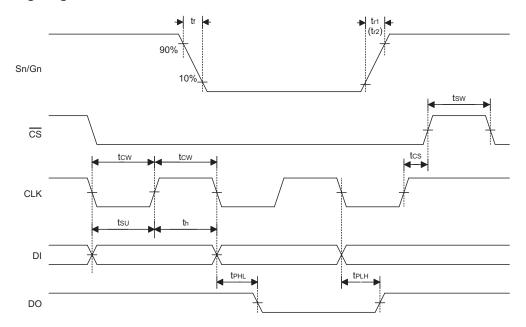


Note: power-on status: 1/16 pulse width is set and the display is turned off. Key scanning will be stopped during power-on status.

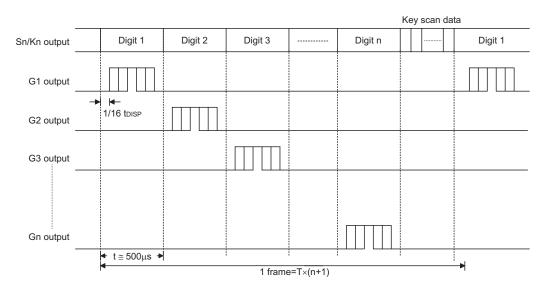
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Timing Diagrams



Key Scanning and Display Timing

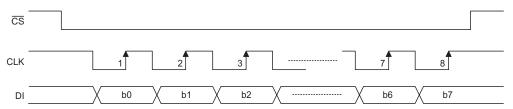


Note: One cycle of key scanning consists of two frames, and data of 16×2 matrixes is stored in the RAM.

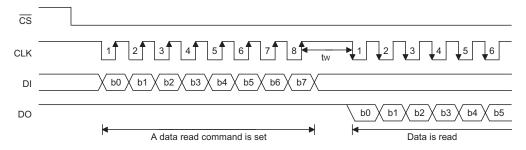


Serial Communication Format

• Reception (command/data write)



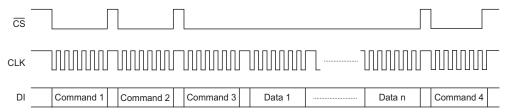
• Transmission (data read)



Be sure to connect an external pull-high resistor to this pin ($1k\Omega$ to $10k\Omega$).

Note: When data is read, a wait time " t_W " of $1\mu s$ is necessary.

• Updating display memory by incrementing address



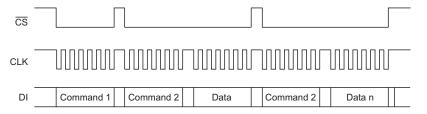
Note: Command 1: sets display mode

Command 2: sets data
Command 3: sets address

Data 1 to n: transfers display data (36 bytes max.)

Command 4: controls display

· Updating specific addresses

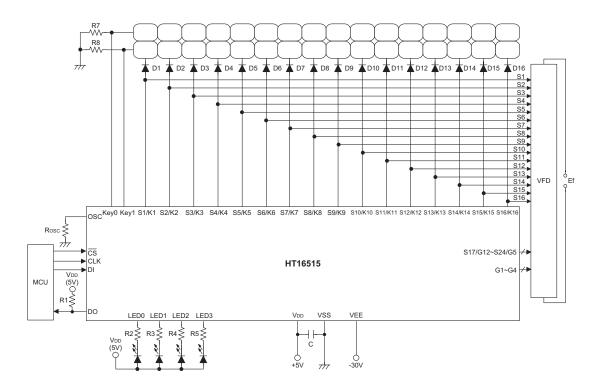


Note: Command 1: sets data Command 2: sets address

Data: display data



Application Circuits



Note: R_{OSC} =82 $k\Omega$ for oscillator resistor

R1=1~10k Ω for external pull-high resistor

R2~R6=750Ω~1.2kΩ

R7~R8=10k Ω for external pull-low resistor

D1~D6=1N4001

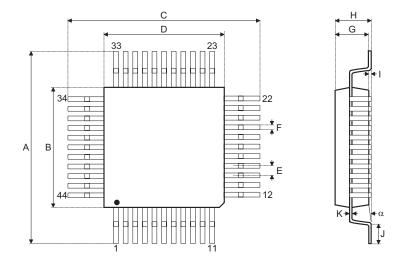
Ef=Filament voltage for VFD

 $C=0.1 \mu F \sim 1.0 \mu F$



Package Information

44-pin QFP (10×10) Outline Dimensions



Symbol	Dimensions in mm					
	Min.	Nom.	Max.			
А	13	_	13.40			
В	9.90	_	10.10			
С	13	_	13.40			
D	9.90	_	10.10			
E	_	0.80	_			
F	_	0.30	_			
G	1.90	_	2.20			
Н	_	_	2.70			
I	_	0.10	_			
J	0.73	_	0.93			
K	0.10	_	0.20			
α	0°	_	7°			



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